R adiation-induced m agnetoresistance oscillations in two-dim ensional electron system s under bichrom atic irradiation

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We analyze the magnetoresistance R_{xx} oscillations in high-mobility two-dimensional electron systems induced by the combined driving of two radiation elds of frequency $!_1$ and $!_2$, based on the balance-equation approach to magnetotransport for high-carrier-density systems in Faraday geometry. It is shown that under bichrom atic irradiation of $!_2$ 1:5!, most of the characterstic peak-valley pairs in the curve of R_{xx} versus magnetic eld in the case of monochromatic irradiation of either $!_1$ or $!_2$ disappear, except the one around $!_1=!_c$ 2 or $!_2=!_c$ 3. R_{xx} oscillations show up mainly as new peak-valley structures around other positions related to multiple photon processes of mixing frequencies $!_1 + !_2$, $!_2 - !_1$, etc. M any minim a of these resistance peak-valley pairs can descend down to negative with enhancing radiation strength, indicating the possible bichromatic zero-resistance states.

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I. IN TRODUCTION

Since the discovery of radiation induced magoscillations (R IM O s) netorersistance and zem-(ZRS) in ultra-high m obilresistance states system s,^{1,2,3,4} two-dimensional (2D) ity electron experim ental^{5,6,7,8,9,10,11,12,13,14} trem endous and theoretical^{15,16,17,18},19,20,21,22,23,24,25,26,27,28,29,30,31,32,33,34 e orts have been devoted to study this exciting phenomenon and a general understanding of it has been reached. Under the in uence of a microwave radiation of frequency f = !=2, the low-tem perature m agnetoresistance R_{xx} of a 2D electron gas (EG), exhibits periodic oscillation as a function of the inverse magnetic eld. The R IM Os feature the periodical appearance of peakvalley pairs around $!=!_{c}=1;2;3;4;$, i.e. a m axim um at $!=!_c = j$ $_{j}$ and a minimum at $!=!_{c}=j+_{j}^{+}$, with j = 1;2;3;4;and $0 \leq 1=4$. Here $!_c$ is the cyclotron frequency and !=! c = j are the node points of the oscillation. With increasing the radiation intensity the amplitudes of the peak-valley oscillations increase and the resistance R_{xx} around the minima of a few low est-j pairs can drop down towards negative direction but will stop when a vanishing resistance is reached, i.e. ZRS.

addition to these basic features, Tn secpeak-valley pair structures were also obondary experim entally^{3,4,6,7,8,11,13} served and predicted theoretically^{23,31} around $!=!_c = 1=2;3=2$ and 2/3. They were referred to the e ect of two-and three-photon processes and their minim a were shown also to be able to develop into negative value when increasing the radiation further. 23 Recent measurement at 27 GHz with intensi ed m icrowave intensity,¹⁴ con m ed these mutliphoton-related peak-valley pairs and the ZRSs developed from their minima. A careful theoretical analysis with enhanced radiation convincingly reproduced these structures and predicted more peak-valley pairs related to multiphoton processes.35

D espite intensive experimental and theoretical studies have been done in the case of monochromatic irradiation, further investigations beyond this conguration are highly desirable for a deeper understanding of this fascinating phenomenon. An easy way is to study the response of the 2D system to a bichromatic radiation, which apparently can not be reduced simply to the superposition of the system response to each monochromatic radiation. Thus the presence of a second radiation of different frequency could provide additional insight into the problem of microwave-driven 2D electron system.

Theoretically, e ect of a bichrom atic irradiation on transport of a 2D electron gas was investigated within a model of a clean classical gas, in which K ohn's theorem is violated entirely due to nonparabolicity without invoking Landau quantization.³⁶ Som e features that are speci c to the bichrom atic case, such as new dom ain of m agnetic eld within which the diagonal conductivity is negative, were revealed.

Experim entally, Zudov et al.¹⁴ recently m easured the magnetoresistance of a high-mobility 2D electron system under the combined driving of two radiation elds of frequency $!_1$ and $!_2$, and disclosed features of R IM O s which are quite di erent from those under monochrom atic radiation of frequency $!_1$ or $!_2$. They detected a new resistance minimum under bichrom atic microw ave radiation, which seems to originate from a frequency mixing process, possibly a precursor of bichrom atic ZRS.

In this paper we report our studies on m icrow ave photoresistance response of high-m obility two-dimensional electron systems under bichromatic irradiation, based on the balance-equation approach to magnetotransport for high-carrier-density systems, extended to the case of simultaneous driving of two radiation elds of di erent frequencies. The balance-equation approach, though sem iclassical in nature, has been shown to capture the essence of this radiation-induced nonlinear magnetotransport quantitatively.^{23,31} Under bichromatic irradiation of !₂ 15!₁, we nd that most of the characteristic peak-valley pairs in the curve of R_{xx} versus magnetic eld in th case of monochrom atic irradiation of either $!_1$ or $!_2$ disappear, except the one around $!_1=!_c = 2$ or $!_2=!_c = 3$. R_{xx} oscillations show up mainly as new peak-valley structures around other positions related to multiple photon processes of mixing frequencies $!_1 + !_2$, $!_2 = !_1$, etc.

II. BALANCE EQUATIONS UNDER BICHROMATIC RADIATION

The derivation of balance equations under bichrom atic radiation follows that of monochrom atic radiation.³¹ The nature of the balance-equation approach and its applicability to radiation-driven magnetotransport in highmobility 2D electron systems of high carrier density, was exam ined closely in Ref.31. We refer the readers to it for detail.

In the case of bichrom atic radiation we consider that a dc or slow ly time-varying electric eld E_0 and two high frequency (HF) elds

$$E_{1}(t) = E_{1s} \sin(!_{1}t) + E_{1c} \cos(!_{1}t)$$
 (1)

and

$$E_{2}$$
 (t) $E_{2s} \sin (!_{2}t) + E_{2c} \cos (!_{2}t)$ (2)

are applied simultaneously in a quasi-2D system consisting of N_e interacting electrons in a unit area of the xy plane, together with a magnetic eld B = (0;0;B)along the z direction. The frequencies $!_1$ and $!_2$ are high enough and their di erence is large enough that ! 1 and $!_2$, as well as $j_1!_1 \quad n_2!_2 j$ (for arbitrary integers n_1 and n_2), are all much larger than 1 = 0, where 0 stands for the scale of the time variation of slow ly varying eld E_0 , or the time scale within which one carries out the transport m easurem ent, whichever the shorter. The approach is based on the separation of the center-of-m ass motion from the relative electron motion of the electrons and describes the transport state of a high-carrier-density many-electron system under radiation elds in terms of a rapidly tim e-varying electron drift velocity oscillating at both base radiation frequencies, $v(t) = v_1(t) + v_2(t)$, with

$$v_1 (t) = v_{1c} \cos(!_1 t) + v_{1s} \sin(!_1 t);$$
 (3)

$$v_2(t) = v_{2c} \cos(!_2 t) + v_{2s} \sin(!_2 t);$$
 (4)

$$m \frac{dv_0}{dt} = eE_0 + e(v_0 - B) + \frac{F_0}{N_e};$$
 (5)

$$N_{e}E_{0} \quad \forall + S_{p} \quad W = 0; \tag{6}$$

with v_{1c} and v_{1s} determined by

$$m !_1 v_{1c} = eE_{1s} + e(v_{1s} B);$$
 (7)

$$m !_1 v_{1s} = eE_{1c} + e(v_{1c} B);$$
 (8)

and v_{2c} and v_{2s} determined by

$$m !_2 v_{2c} = e E_{2s} + e (v_{2s} B);$$
 (9)

$$m !_2 v_{2s} = e E_{2c} + e (v_{2c} B)$$
: (10)

Here e and m are the electron charge and e ective m ass,

$$F_{0} = \begin{pmatrix} X & & X^{k} \\ & U & (q_{k}) \end{pmatrix}^{2} & J_{n_{1}}^{2} (_{1}) J_{n_{2}}^{2} (_{2}) \\ & & q_{k} & n_{1}; n_{2} = 1 \\ & & q_{k-2} (q_{k}; !_{0} & n_{1}!_{1} & n_{2}!_{2}) (11) \end{pmatrix}$$

is the dam ping force of the moving center-of-m ass,

$$S_{p} = \begin{pmatrix} X & & & X^{d} \\ & & & U & (q_{k}) \end{pmatrix}^{2} & & J^{d}_{n_{1}} & J^{2}_{n_{1}} (1) J^{2}_{n_{2}} (2) \\ & & & & n_{1}, n_{2} = 1 \\ & & & (n_{1}!_{1} + n_{2}!_{2})_{2} (q_{k}; !_{0} & n_{1}!_{1} & n_{2}!_{2}) (12) \end{pmatrix}$$

is the averaged rate of the electron energy absorption from the ${\rm H\,F}$ $\,$ edds, and

$$W = \frac{X}{q} \frac{M}{n_{1};n_{2}=1} J_{n_{1}}^{2} (1) J_{n_{2}}^{2} (2)$$

$$q \frac{n_{1};n_{2}=1}{q 2(q; !_{0} + q n_{1} !_{1} n_{2} !_{2}) (13)}$$

is the average rate of the electron energy dissi-In the above equations, pation to the lattice. $J_{n_1}\left({\,}_1 \right)$ and $J_{n_2}\left({\,}_{\hat{B}} \right)$ are Bessel functions of order n_1 and n_2 , 1 $(q_k \quad \Psi_c)^2 + (q_k \quad \Psi_s)^2 = !_1, 2$ $(q_k \quad y_c)^2 + (\overline{q_k \quad y_s})^2 = !_2$, and $!_0$ q_k y. Here $(q_k; q_k)$ stands for the in-plane wavevector, U (q_k) is q. the elective in purity scattering potential, and $_2(q_k;)$ is the imaginary part of the electron density correlation function of the quasi-2D system in the magnetic eld. In Eq. (13), q represents the 3D wavevector $(q_k;q_z)$ plus the branch index , and the sum mation is for all possible 3D phonon modes of frequency q having electronphonon scattering matrix element M (q). $_2$ (q;) = $2_{2}(q_{k};)[n(q=T) n(=T_{e})] (w \pm n(x) 1=(e^{x} 1))$ is the imaginary part of the electron-phonon correlation function. The $_2(q_k;)$ function of a 2D system in a magnetic eld can be expressed in the Landau representation:³⁹

$${}_{2}(\mathbf{q}_{k};) = \frac{1}{2} \frac{1}{2} \prod_{B}^{2} C_{n;n^{0}} (l_{B}^{2} q_{k}^{2} = 2) {}_{2}(n;n^{0};); (14)$$

$${}_{2}(n;n^{0};) = \frac{2}{2} \frac{2}{d} [f(") f(" +)]$$

$$\operatorname{Im} G_{n}(" +) \operatorname{Im} G_{n^{0}}("); (15)$$

where $C_{n;n+1}(Y)$ n![(n + 1)!] ¹Y ¹e ^Y $[L_n^1(Y_p]^2 w \pm h]$ $L_n^1(Y)$ the associate Laguerre polynom ial, l_e 1=jeB j is the magnetic length, f (") = fexp[(") =T_e] + 1g ¹ is the Ferm i distribution function at electron temperature T_e. The density of states of the n-th Landau level is modeled with a G aussian form t^{40}

$$\operatorname{Im} G_{n}(") = \left(\begin{array}{c} p \\ 2 \end{array} \right) \exp \left[2 (" "_{n})^{2} = \begin{array}{c} 2 \end{array} \right]; \quad (16)$$

having a half-width

$$= \frac{8e!_{c}}{m_{0}}^{1=2}$$
(17)

around the level center " $_n = n!_c$. Here $!_c = eB = m$ is the cyclotron frequency, $_0$ is the linear mobility at lattice temperature T in the absence of the magnetic eld, and is a sem i-empirical parameter to take account of the di erence of the transport scattering time $_m$ determining the mobility $_0$, from the single particle lifetim e $_s$ related to Landau level broadening.

For time-independent v_0 , we immediately deduce the transverse and longitudinal dc resistivities from Eq.(5):

$$R_{xy} = B = N_e e;$$
 (18)

$$R_{xx} = F_0 \quad y = (N_e^2 e^2 v_0^2):$$
 (19)

The (linear) magnetoresistivity is its $v_0 ! 0$ lim it:

$$R_{xx} = \frac{1}{N_e^2 e^2} \int_{q_k}^{X} q_k^2 j (q_k) j^2$$

$$X^{i} = \int_{n_1, n_2 = -1}^{N_e^2 e^2} J_{n_1}^2 (f_1) J_{n_2}^2 (f_2) \frac{g_{n_1}}{g_{n_2}} = \int_{n_1, n_2 = -1}^{n_1 + n_2 + 2} (f_2) f_2$$

W e assume that the 2DEG is contained in a thin sam – ple suspended in vacuum at plane z = 0. W hen both electrom agnetic waves illum inate upon the plane perpendicularly with the incident electric elds E_{i1}(t) = E_{i1s} sin(!₁t) + E_{i1c} cos(!₁t) and E_{i2}(t) = E_{i2s} sin(!₂t) + E_{i2c} cos(!₂t), the HF electric elds in the 2DEG, determined by the electrodynamic equations, are

$$E_{1}(t) = \frac{N_{e}ev_{1}(t)}{2_{0}c} + E_{i1}(t); \qquad (21)$$

$$E_{2}(t) = \frac{N_{e}ev_{2}(t)}{2_{0}c} + E_{i2}(t):$$
 (22)

U sing this E₁ (t) in Eqs. (7) and (8), and E₂ (t) in Eqs. (9) and (10), the oscillating velocity v_{1c} and v_{1s} (and thus the argument 1) are explicitly expressed in terms of incident eld E_{ils} and E_{ilc}, and the oscillating velocity v_{2c} and v_{2s} (and thus the argument 2) are explicitly expressed in terms of incident eld E_{i2s} and E_{i2c}. Therefore, in the case of weak measuring current limit (v_0 ! 0) we need only to solve the energy balance equation S_p W = 0 to obtain the electron temperature T_e under given incident radiation elds, before directly calculating the linear magnetoresistivity from Eq. (20).

W ithin certain eld range, the magnetoresistivity R $_{\rm xx}$ given by Eq.(19) can be negative at small v₀, but will change towards the positive direction with increasing v₀ and passes through zero at a nite v₀,²³ in plying that the tim e-independent small-current solution is unstable and a spatially nonuniform ¹⁹ or a tim e-dependent solution³⁴ m ay develop, which exhibits measured zero resistance. Therefore we identify the region where a negative dissipative magnetoresistance develops as that of the ZRS.

The sum mations over n_1 and n_2 in Eqs. (11), (12) and (13) include all possible electron transition processes assisted by real and virtual photons of frequency $!_1$ and $!_2$. The $n_1 > 0$ terms represent all possible electron transitions with simultaneous absorption of n_1 photons of frequency $!_1$, while $n_1 < 0$ terms represent all possible electron transitions with simultaneous emission of $jn_1 j$ photons of frequency $!_1$. We call these electron transitions the $jn_1 j!_1$ -photon assisted processes. The same for $jn_2 j!_2$ -photon assisted processes. The $n_1 = 0$ terms represent electron transitions assisted by virtual $!_1$ -photons (all possible emission and absorption of same num ber of $!_1$ -photons), and $n_2 = 0$ terms represent electron transitions assisted by virtual $!_2$ -photons.

III. NUMERICAL RESULTS

As indicated by experiments,⁴¹ in ultra-clean GaAsbased 2D samples having mobility of order of 10^3 m²/Vs, the remote donor scattering is responsible for merely

10% or less of the total m om entum scattering rate. The dominant contribution to the momentum scattering com es from short-range scatterers such as residual in purities or defects in the background. Therefore, as in Ref.31, we assume that the dom inant elastic scatterings contributing to the resistance and energy absorption are due to short-range in purities random ly distributed throughout the GaAs region in the num erical calculations. The impurity densities are determined by the requirem ent that electron total linear m obility at zero magnetic eld equals the giving value at lattice tem perature T. Since R IM O measurements are at low temperatures, the direct phonon contributions to S_p and F_0 (R_{xx}) can be neglected. Nevertheless, to calculate the electron energy dissipation to the lattice, W , we take account of scatterings from bulk longitudinal acoustic (LA) and transverse acoustic (TA) phonons (via the deform ation potential and piezoelectric couplings), as well as from longitudinal optical (LO) phonons (via the Frohlich coupling) in the G aA s-based system . The relevant m aterial and coupling param eters are taken typical values of GaAs⁴² electron e ective mass m = 0:068 m $_{\odot}$ (m $_{\odot}$ is the free electron m ass), transverse sound speed $v_{st} = 2:48$ 10° m /s, longitudinal sound speed v_{sl} = 5.29 10^{3} m /s, acoustic deformation potential = 8:5 eV, piezoelectric constant $e_{14} = 1:41 \quad 10^9 \text{ V/m}$, dielectric constant



FIG.1: (Color online) The magnetoresistivity R_{xx} versus the inverse magnetic eld 1=B for a GaAs-based 2DEG with $N_e = 3.0 \quad 10^{15} \text{ m}^{-2}$, $_0 = 2000 \text{ m}^2/\text{V} \text{ s}$ and = 5, inradiated simultaneously by to two microwaves with frequencies $!_1=2$ = 31GHz and $!_2=2$ = 47GHz having four sets of incident amplitudes $E_{11} = E_{12} = 1:4;2;3;$ and 4 V/cm at lattice temperature T = 1K. $!_c = eB = m$ is the cyclotron frequency at the magnetic eld B.



FIG.2: (C olor online) The m agnetoresistivity R_{xx} versus the inverse m agnetic eld 1=B for the same system as described in Fig.1. The thin curves are under m onochrom atic irradiation either of frequency $!_1=2 = 31 \text{ GHz}$ and incident am plitude $\text{E}_i = 3\text{ V/cm}$ (dot curve), or of frequency $!_1=2 = 47 \text{ GHz}$ and incident am plitude $\text{E}_i = 3\text{ V/cm}$ (solid curve). The thick curves are under bichrom atic irradiation of frequencies $!_1=2 = 31 \text{ GHz}$ and $!_2=2 = 47 \text{ GHz}$ having incident am plitude $\text{E}_{i1} = 2 = 31 \text{ GHz}$ and $!_2=2 = 47 \text{ GHz}$ having incident am plitude $\text{E}_{i1} = 2 = 31 \text{ GHz}$ and $!_2=2 = 47 \text{ GHz}$ having incident am plitude $\text{E}_{i1} = 12 = 31 \text{ GHz}$ m (solid curve) or 35 V/cm (dash-dot curve). The lattice tem perature is T = 1 K.

= 12:9, m aterial m ass density $d = 5.31 \text{ g/cm}^3$.

The numerical calculations are performed for xdirection (parallel to E_0) linearly polarized incident m icrowave elds $E_{i1s} = (E_{i1};0); E_{i1c} = 0$ and $E_{i2s} = (E_{i2};0); E_{i2c} = 0$].

Figure 1 shows the calculated magnetoresistivity R_{xx} versus the inverse magnetic eld for a GaAs-based 2D



FIG .3: (Color online) The same as Fig.2, but m agnetoresistivity R_{xx} is shown as a function of the magnetic eld B.

system having electron density N_e = $3.0 \quad 10^{15} \text{ m}^{-2}$, linearm obility $_{0} = 2000 \text{ m}^{2}/\text{V} \text{ s and broadening param eter}$ = 5, simultaneously irradiated by two microwaves of frequencies $!_1=2 = 31 \text{ GHz}$ and $!_2=2 = 47 \text{ GHz}$ with four sets of incident amplitudes $E_{i1} = E_{i2} = 1:4;2;3;$ and 4V/cm at lattice tem perature T = 1K.We see that the bichromatic photoresponse of R_{xx} is unlike that of m onochrom atic irradiation. M ost of the characterizing peak-valley pairs in the curve of R_{xx} versus magnetic eld subjected to monochrom atic irradiation of either ! 1 or $!_2$ disappear. The only exception is the peak-valley pair around $!_1 = !_c \quad 2 \text{ or } !_2 = !_c \quad 3$, which, on the contrary, is som ew hat enhanced in bichrom atic irradiation. New peak-valley pairs appear. Their am plitudes generally increase with increasing the incident eld strengths as indicated in the gure. Most of these pairs exhibit essentially xed node positions while growing amplitudes and their m in in a can drop down into negative.

As in the case of monochrom atic illumination, the appearance of magnetoresistance oscillation in the bichromatic irradiation comes from real photon-assisted electron transitions between di erent Landau levels as indicated in the summation of the electron density-correlation function in Eq. (14). Apparently, all multiple photon processes related to $!_1$ monochromatic radiation and $!_2$ monochromatic radiation are included. In addition, there are multiple photon processes related to mixing $!_1$ and $!_2$ radiation.

W ith three positive integers $n_1; n_2$ and 1 to characterize a multiple photon assisted electron transition, we use the symbol $n_1!_1 + n_2!_2$: 1 to denote a process during which an electron jumps across 1 Landau level spacings with simultaneous absorption of n_1 photons of frequency $!_1$ and n_2 photons of frequency $!_2$, or simultaneous em ission of n_1 photons of frequency $!_1$ and n_2 photons of frequency $!_2$; and use the symbol $n_1!_1 - n_2!_2$: 1 to denote a process during which an electron jumps across 1 Landau level spacings with simultaneous absorption of n_1 photons of frequency $!_1$ and em ission of n_2 photons of

frequency $!_2$, or simultaneous em ission of n_1 photons of frequency $!_1$ and absorption of n_2 photons of frequency $!_2$ (thus the sym boln₂ $!_2$ $n_1!_1$: lhas the sam e m eaning as $n_1!_1$ $n_2!_2$: 1). The symbol $n_1!_1$: 1 indicates a process during which an electron jum ps across l Landau level spacings with the assistance of n_1 real (em ission or absorption) $!_1$ -photons and virtual $!_2$ -photons. So does the symbol $n_2!_2$: l. We not that the processes represented by $n_1!_1 + n_2!_2$: l contribute, in the R_{xx} -versus-! c=! curve, a structure consisting of a minimum and a maximum on both sides of $!_{c} = !_{1} = n_{1} (1 + n_{2} !_{2} = n_{1} !_{1}) = 1$ or $!_c = !_2 = n_2 (1 + n_1 !_1 = n_2 !_2) = 1$. And those by $n_1 !_1$ $n_2!_2$: 1 (assume $n_1!_1 > n_2!_2$) contribute a minimum maximum pair around $!_{c}=!_{1}=n_{1}(1 n_{2}!_{2}=n_{1}!_{1})=1$ or $!_{c}=!_{2} = n_{2} (n_{1}!_{1}=n_{2}!_{2} 1)=1.$

From the structure of R $_{\rm XX}$ curves with increasing radiation strength in Fig.1 we can clearly identify several peak-valley pairs characteristic of the bichrom atic irradiation. The strongest peak-valley pair is around 2 or !₂=!_c 3, which can be referred to the $!_1 = !_c$ joint contribution from single and multiple photon processes with mono- $!_1$, mono- $!_2$ and mixing $!_1$ and $!_2$, such as $!_2$ $!_1, !_1 : 2, !_2 : 3, 2!_1 : 4, !_1 + !_2 : 5,$. The other peak-valley pairs which are clearly identied include that around $!_1 = !_c$ 0:4 referred to $!_1 + !_2 : 1$,

; that aroung $= !_c$ 0:57 referred to $2!_1 + !_2 : 2$, ; that around=! $_{c}$ 0:8 referred to ! $_{1}$ + ! $_{2}$:2,

; that aroung=! $_{c}$ 1:14 referred to 2! $_{1}$ + ! $_{2}$:4,

; that aroung $= !_c$ 2:84 referred to $2!_1 + !_2$:10,

. They are indicated in the gure. The minim a of all B these peak-valley pairs can drop down to negative when increasing the strengths of the radiation eld, indicating the the possible locations of the bichrom atic ZRSs.

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taneous irradiation of two microwaves having frequencies $!_1=2 = 31 \text{ GHz}$ and $!_2=2 = 47 \text{ GHz}$ with incident amplitudes $E_{i1} = E_{i2} = 3$ and 3.5 V/cm, together with those subjected to single microwave radiation of frequency $!_1=2 = 31 \text{ GHz with incident am pli-}$ tude $E_i = 3V/cm$, or of frequency $!_1=2 = 31GHzwith$ incident am plitude $E_i = 3V/cm$.

This gure is redrawn in Fig.3 showing R_{xx} as a function of the magnetic eld to give a clearer view in the higher magnetic eld side. It indicates a possible bichromatic ZRS around $!_c = !_1$ 22 or !_c=!₂ 1:5 arising from R_{xx} droping to negative at the minimum of the valley-peak pair around $!_c = !_1 = 2.5$ associated with the m ixing biphoton process $!_1 + !_2 : 1$. This result is in agreem ent with the recent experim ental observation on the possible precursor of bichrom atic ZRS.¹⁴

Note added: A fler the acceptance of this paper by Phys. Rev. B, we read a further report of the bichromatic m icrowave photoresistance measurement.⁴³ The experim ental peak/valley positions exhibit a good agreem ent with the present theoretical results in a wide m agnetic eld range. Our predicted peaks around $!_{c}=!_{1}=$ 0:77;0:52;0:37, and valley at $!_c=!_1 = 0:33$ (Fig.3), quite accurately $(m = 0.068 m_e)$ reproduce the observed peaks around B 570;380;275G and the valley around 250G.

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